

# Device Modeling Report

COMPONENTS : VOLTAGE COMPARATOR  
PART NUMBER : LM311N/14  
MANUFACTURER : NATIONAL



**Bee Technologies Inc.**

## **BJT MODEL**

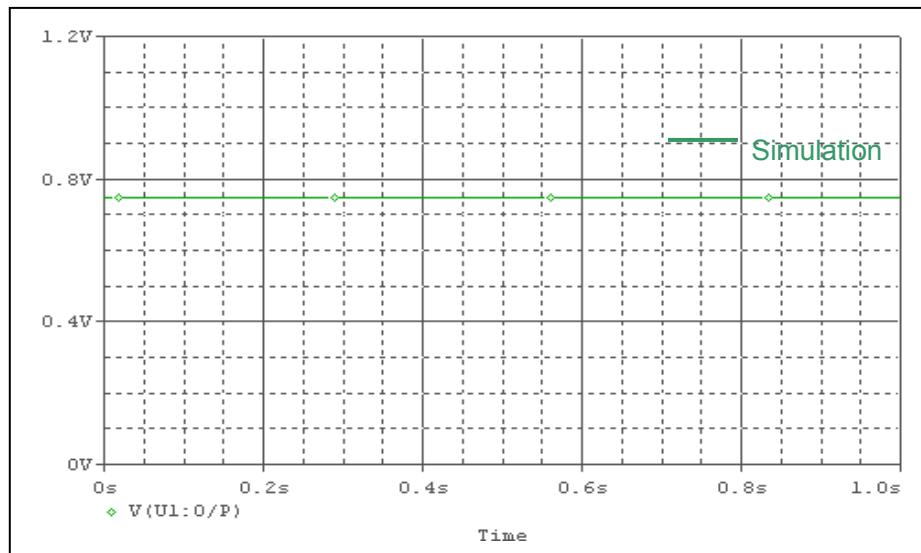
| Pspice model parameter | Model description                             |
|------------------------|---|
| IS                     | Saturation Current                            |
| BF                     | Ideal Maximum Forward Beta                    |
| CJC                    | Zero-bias Collector-Base Junction Capacitance |
| TF                     | Forward Transit Time                          |
| TR                     | Reverse Transit Time                          |

## **DIODE MODEL**

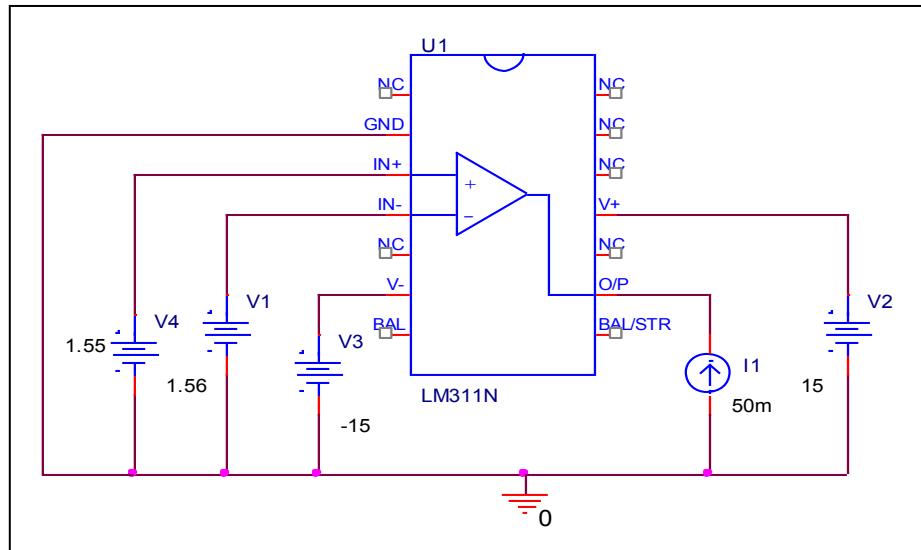
| Pspice model parameter | Model description  |
|------------------------|--------------------|
| IS                     | Saturation Current |
| RS                     | Series Resistance  |

## Output Low Voltage

Simulation result



Evaluation Circuit

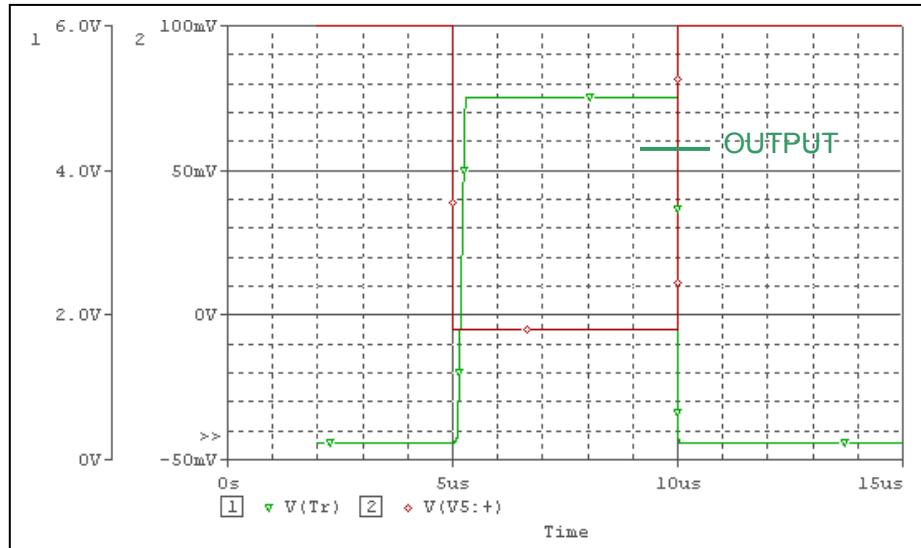


Companson Table

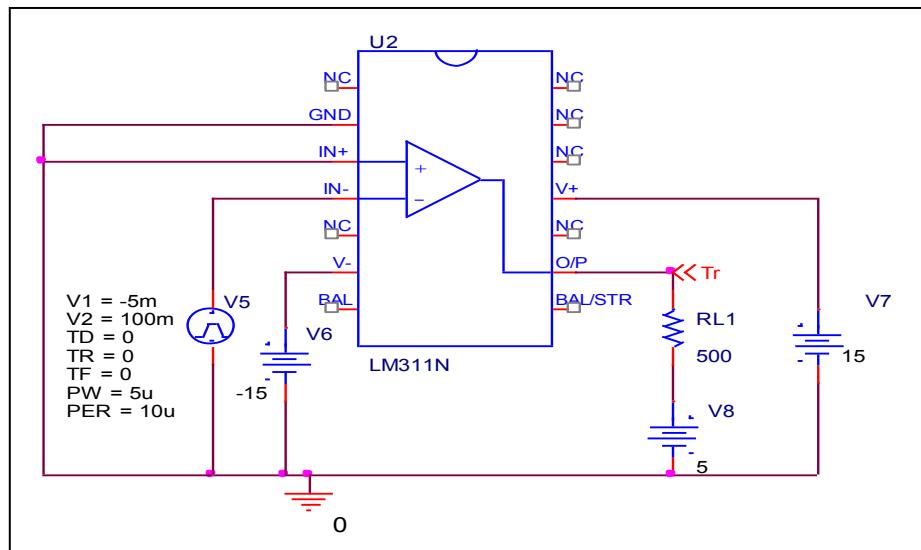
| I <sub>O</sub> = 50mA | Measurement | Simulation | %Error |
|-----------------------|-------------|------------|--------|
| V <sub>ol</sub> (V)   | 0.75        | 0.749735   | -0.035 |

## Response time (Rise time and Transition time)

Simulation result



Evaluation Circuit

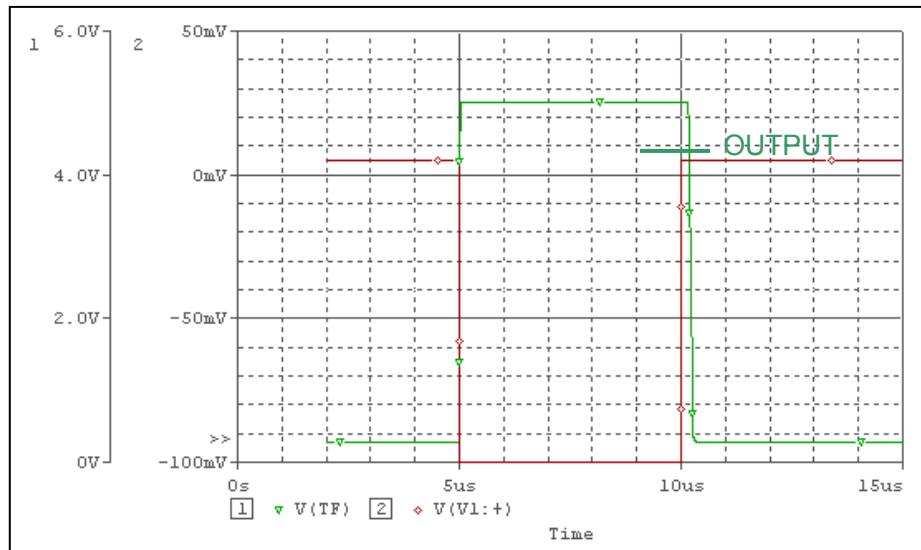


Companson Table

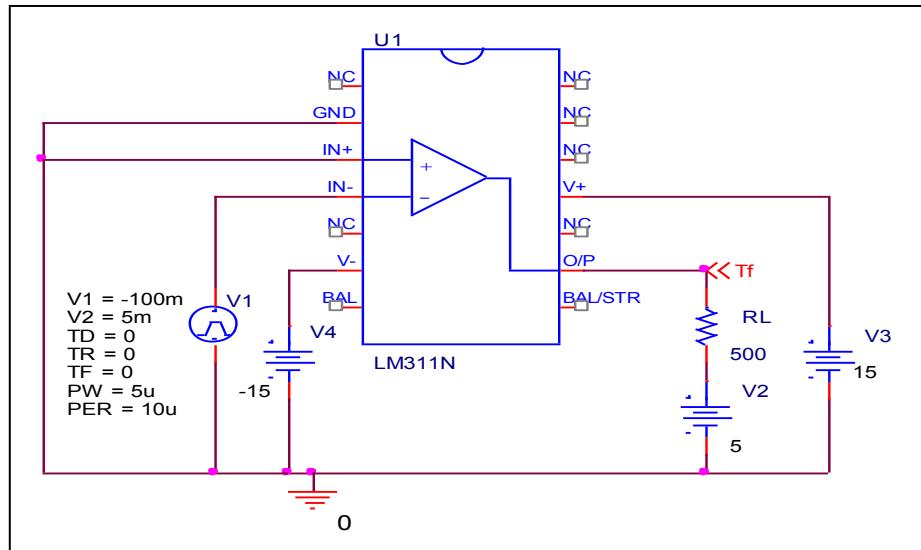
|                        | Measurement | Simulation | % Error |
|------------------------|-------------|------------|---------|
| Rising delay time (us) | 0.125       | 0.124079   | -0.737  |
| Transition time (us)   | 0.140       | 0.13897    | -0.736  |

## Response time (Falling time)

### Simulation result



### Evaluation Circuit

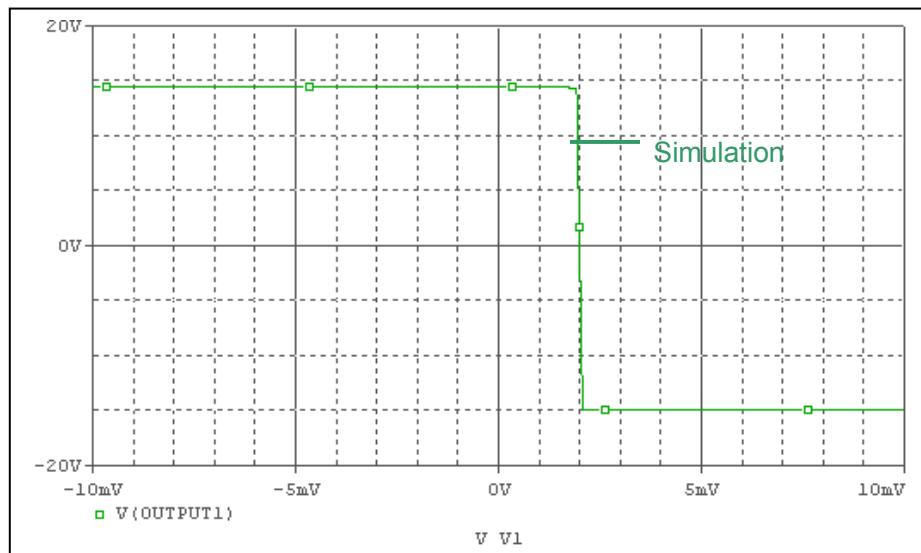


### Companson Table

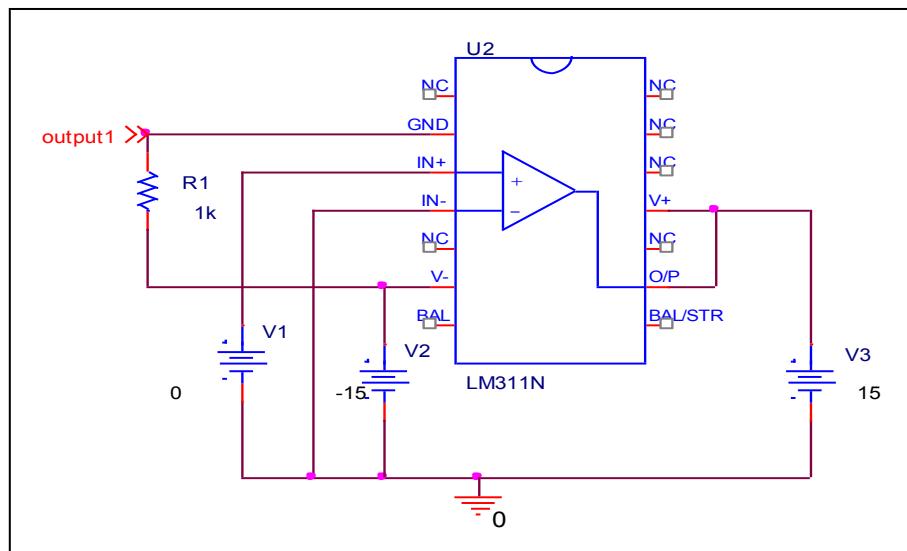
|                         | Measurement | Simulation | % Error |
|-------------------------|-------------|------------|---------|
| Falling delay time (us) | 0.175       | 0.174974   | -0.015  |

## Input Offset Voltage Characteristics

Simulation result



Evaluation Circuit

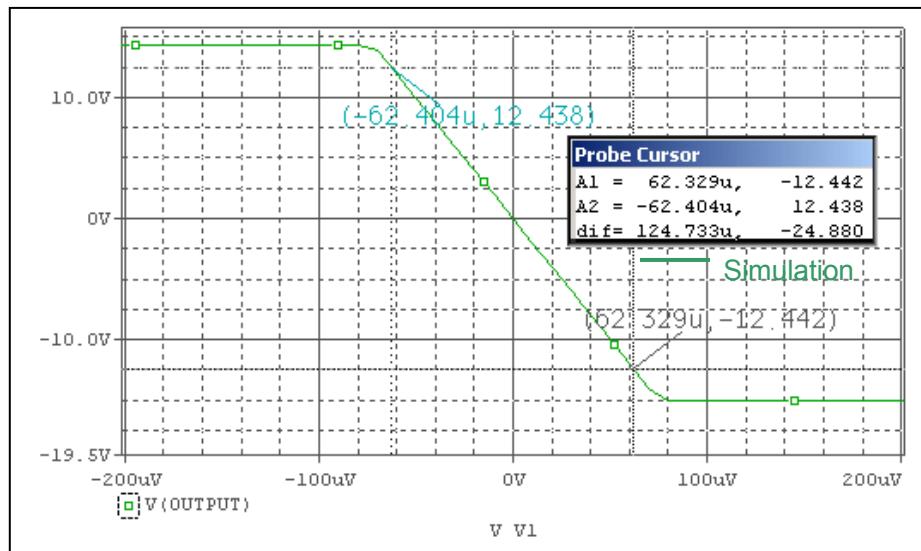


Companson Table

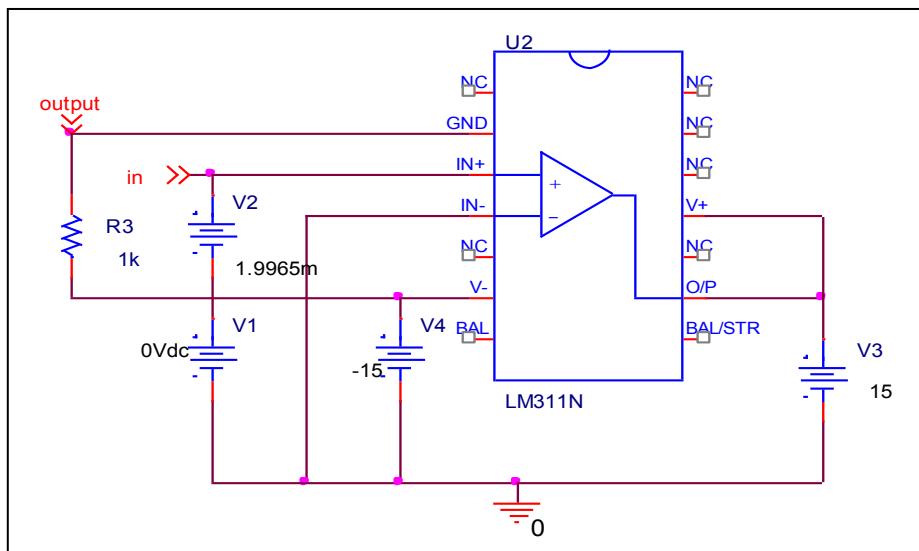
|               | Measurement | Simulation | %Error |
|---------------|-------------|------------|--------|
| $V_{io}$ (mV) | 2           | 1.9965     | -0.175 |

## Av Characteristics

Simulation result



Evaluation Circuit



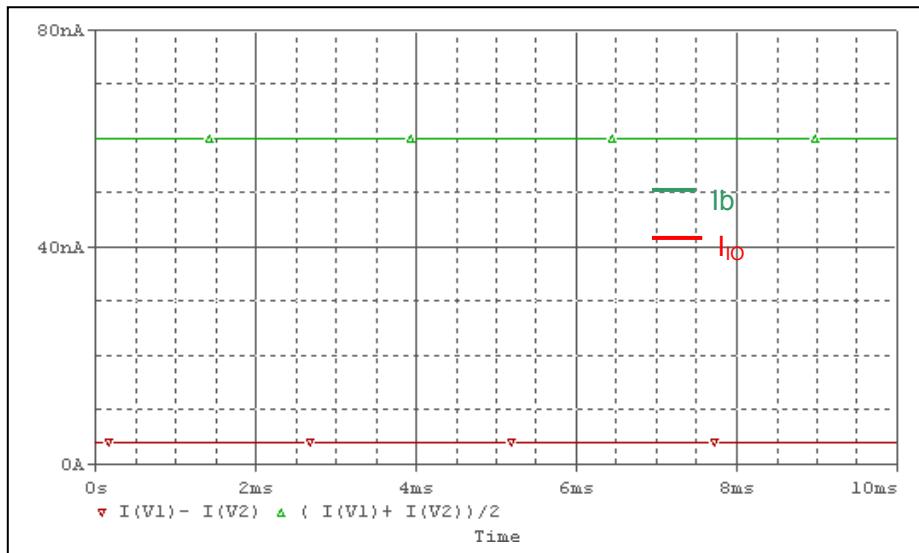
$$Av = 24.880 / 124.733u$$

Companson Table

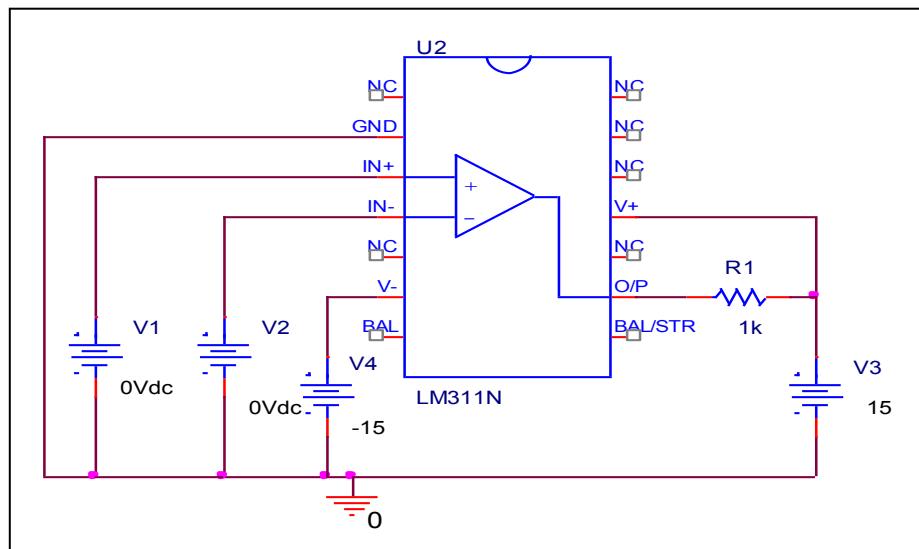
| $R_L = 1k\Omega$ | Measurement | Simulation | %Error |
|------------------|-------------|------------|--------|
| Av (V/mV)        | 200         | 199.466    | -0.267 |

## Input Bias Current Characteristics

Simulation result



Evaluation Circuit



Compasion Table

|         | Measurement | Simulation | % Error |
|---------|-------------|------------|---------|
| Ib (nA) | 100         | 100.059    | 0.059   |
| Io (nA) | 6           | 6.0075     | 0.125   |